DM74LS30 8-Input NAND Gate

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# DM74LS30 8-Input NAND Gate

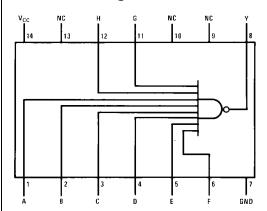
## **General Description**

This device contains a single gate which performs the logic NAND function.

# **Ordering Code:**

Order Number	Package Number	Package Description
DM74LS30M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
DM74LS30N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Devices also available	in Tape and Reel. Specify	by appending the suffix letter "X" to the ordering code.

### **Connection Diagram**



## Function Table

 Y = ABCDEFGH

 Inputs
 Output

 A thru H
 Y

 All Inputs H
 L

 One or More
 H

 Input L
 Input L

H = HIGH Logic Level L = LOW Logic Level

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### Absolute Maximum Ratings(Note 1)

I		
	Supply Voltage	7V
	Input Voltage	7V
	Operating Free Air Temperature Range	$0^{\circ}C$ to $+70^{\circ}C$
	Storage Temperature Range	-65°C to +150°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

### **Recommended Operating Conditions**

Symbol	Parameter	Min	Nom	Max	Units
V <sub>CC</sub>	Supply Voltage	4.75	5	5.25	V
V <sub>IH</sub>	HIGH Level Input Voltage	2			V
V <sub>IL</sub>	LOW Level Input Voltage			0.8	V
I <sub>OH</sub>	HIGH Level Output Current			-0.4	mA
I <sub>OL</sub>	LOW Level Output Current			8	mA
T <sub>A</sub>	Free Air Operating Temperature	0		70	°C

## **Electrical Characteristics**

over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 2)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$			-1.5	V
V <sub>OH</sub>	HIGH Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$	2.7	3.4		V
V <sub>OL</sub>	LOW Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$		0.35	0.5	v
		$I_{OL} = 4 \text{ mA}, V_{CC} = Min$		0.25	0.4	
l <sub>l</sub>	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 7V$			0.1	mA
I <sub>IH</sub>	HIGH Level Input Current	$V_{CC} = Max, V_I = 2.7V$			20	μΑ
lıL	LOW Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-0.4	mA
los	Short Circuit Output Current	V <sub>CC</sub> = Max (Note 3)	-20		-100	mA
I <sub>CCH</sub>	Supply Current with Outputs HIGH	V <sub>CC</sub> = Max		0.35	0.5	mA
ICCL	Supply Current with Outputs LOW	V <sub>CC</sub> = Max		0.6	1.1	mA
Note 2: All	typicals are at V <sub>CC</sub> = 5V, T <sub>A</sub> = 25°C.	•	•	•	•	•

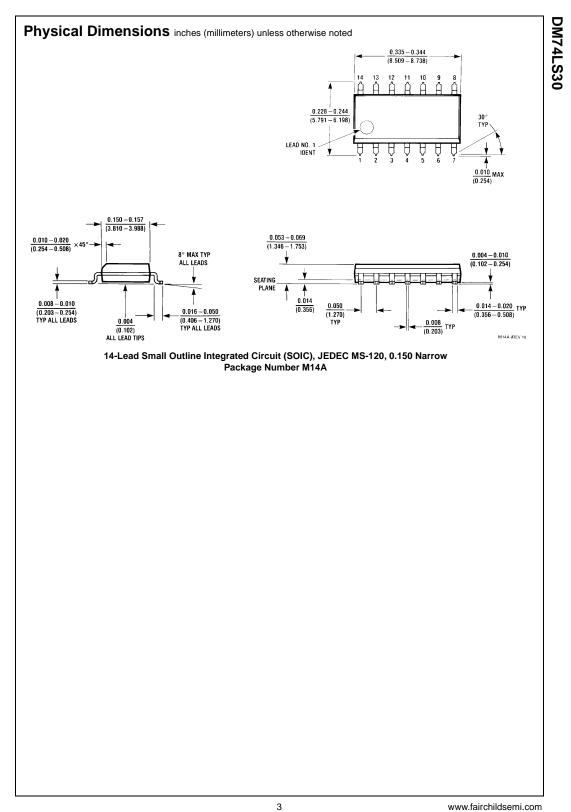
Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

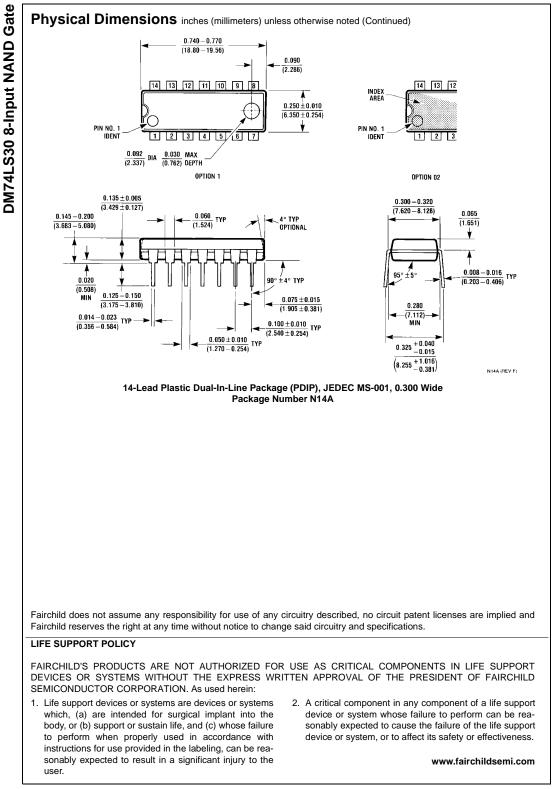
## **Switching Characteristics**

at  $V_{CC}=5V$  and  $T_A=25^\circ C$  (See Section 1 for Test Waveforms and Output Load)

Min         Max         Min         Max           tPLH         Propagation Delay Time LOW-to-HIGH Level Output         4         12         5         18           tPHL         Propagation Delay Time         4         15         5         20		Parameter	$R_L = 2 k\Omega$				
tpLH     Propagation Delay Time LOW-to-HIGH Level Output     4     12     5     18       tpHL     Propagation Delay Time     4     15     5     20	Symbol		C <sub>L</sub> = 15 pF		C <sub>L</sub> = 50 pF		Units
LOW-to-HIGH Level Output         4         12         5         18           t <sub>PHL</sub> Propagation Delay Time         4         15         5         20			Min	Max	Min	Max	
t <sub>PHL</sub> Propagation Delay Time 4 15 5 20	t <sub>PLH</sub>	Propagation Delay Time	4	12	5	18	ns
		LOW-to-HIGH Level Output	4				115
HIGH-to-LOW Level Output 4 13 5 20	t <sub>PHL</sub>	Propagation Delay Time	4	15	5	20	ns
		HIGH-to-LOW Level Output	4	15			

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